

Description

The BSH205G2A uses advanced trench technology to provide excellent R $_{DS(ON)}$, low gate chargeand operation with gate voltages as low as 1.8V. This device is suitable for use as a load switch or in PWM applications.

General Features

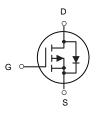
$$\begin{split} V_{DS} &= -20 V, I_D = -2.3 A \\ R_{DS(ON)} &< 140 m \, \Omega \, @ \, V_{GS} = -4.5 V \\ R_{DS(ON)} &< 170 m \, \Omega \, @ \, V_{GS} = -2.5 V \end{split}$$

Application

PWM applications Load switch







P-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Brand	Qty(PCS)
BSH205G2A	SOT-23	HXY MOSFET	3000

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	Limit	Unit
VDS	Drain-Source Voltage	-20	V
Vgs	Gate-Source Voltage	±12	V
ID	Drain Current-Continuous	-2.3	A
Ідм	Drain Current-Pulsed (Note 1)	-9	A
PD	Maximum Power Dissipation	0.65	W
Тյ,Тѕтс	Operating Junction and Storage Temperature Range	-55 To 150	°C
Reja	Thermal Resistance, Junction-to-Ambient (Note 2)	178	°C/W



Electrical Characteristics (T_A=25[°]C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	· ·					
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-20		-	V
Zero Gate Voltage Drain Current	IDSS	V _{DS} =-20V,V _{GS} =0V	-	-	-1	μA
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±12V, V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=-250\mu A$	-0.4	-0.7	-1	V
		V_{GS} =-4.5V, I_D =-2A		130	140	mΩ
Drain-Source On-State Resistance	Rds(on)	V _{GS} =-2.5V, I _D =-1.8A		152	170	mΩ
Forward Transconductance	G FS	V _{DS} =-5V,I _D =-2A	4	-	-	S
Dynamic Characteristics (Note4)	<u> </u>			,		
Input Capacitance	C _{lss}		-	285	-	PF
Output Capacitance	Coss	V_{DS} =-10V, V_{GS} =0V,	-	58	-	PF
Reverse Transfer Capacitance	Crss	F=1.0MHz	-	32	-	PF
Switching Characteristics (Note 4)	i					
Turn-on Delay Time	t _{d(on)}		-	9.8	-	nS
Turn-on Rise Time	tr	V_{DD} =-10V, RL=5 Ω	-	4.9	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =-4.5V, R_{GEN} =3 Ω	-	20.5	-	nS
Turn-Off Fall Time	tf		-	7	-	nS
Total Gate Charge	Qg		-	2.9	-	nC
Gate-Source Charge	Q _{gs}	V_{DS} =-10V,I _D =-2A,	-	0.45	-	nC
Gate-Drain Charge	Qgd	V_{GS} =-4.5V	-	0.75	-	nC
Drain-Source Diode Characteristics	I I					L
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-2A	-	-	-1.2	V
Diode Forward Current (Note 2)	Is		-	-	-2.0	А

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, t ≤ 10 sec.

3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

4. Guaranteed by design, not subject to production



Typical Electrical and Thermal Characteristics

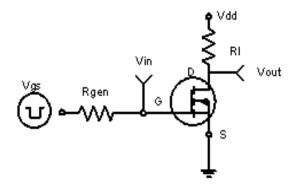


Figure 1:Switching Test Circuit

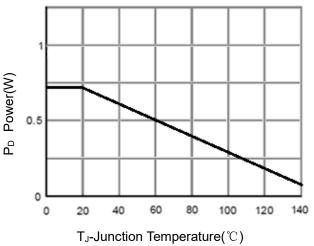
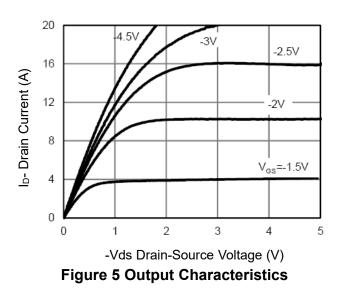


Figure 3 Power Dissipation



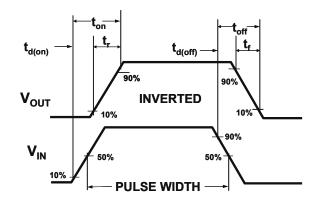


Figure 2:Switching Waveforms

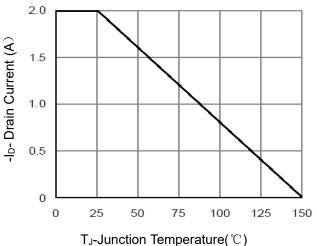
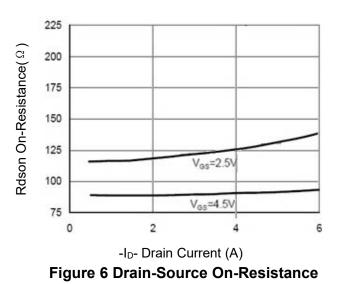
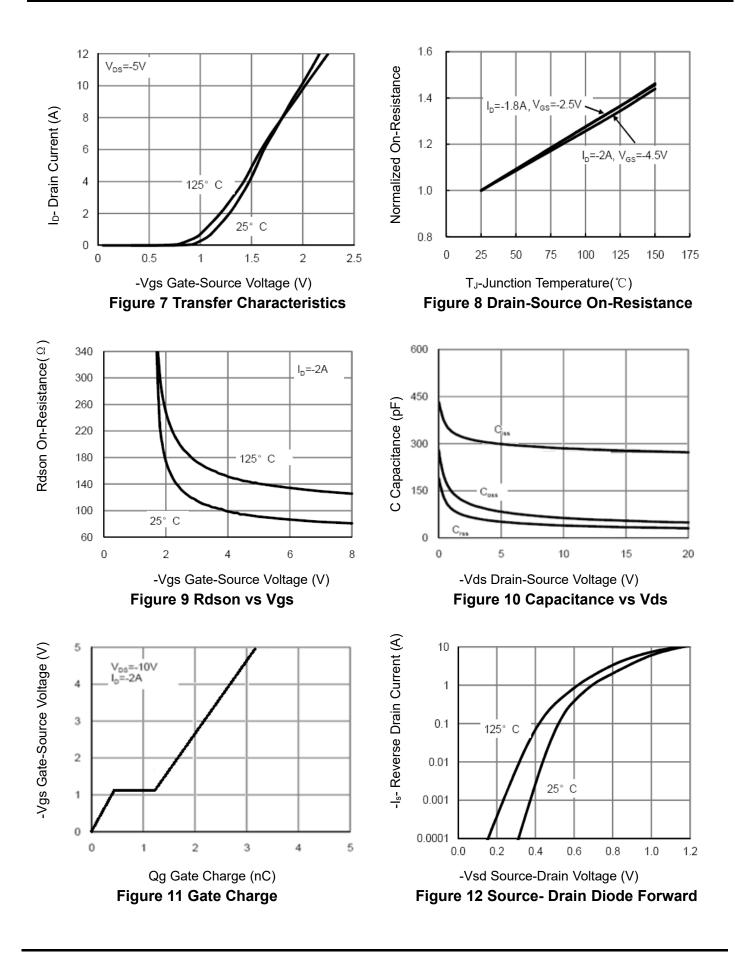


Figure 4 Drain Current









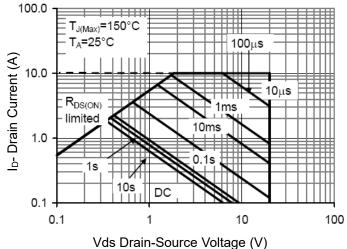


Figure 13 Safe Operation Area

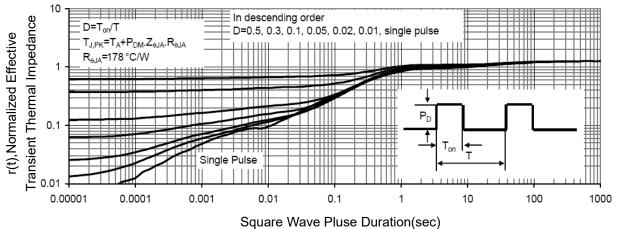
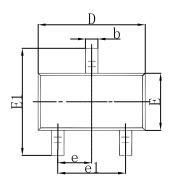
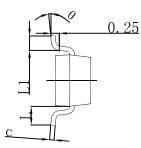


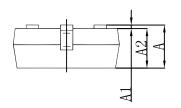
Figure 14 Normalized Maximum Transient Thermal Impedance



SOT-23 Package Outline Dimensions

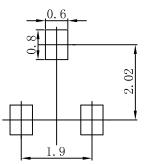






Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
E	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.950 TYP		0.037 TYP		
e1	1.800	2.000	0.071	0.079	
L	0.550 REF		0.022 REF		
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	

SOT-23 Suggested Pad Layout



Note: 1.Controlling dimension:in millimeters.

2.General tolerance:± 0.05mm.
 3.The pad layout is for reference purposes only.



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